

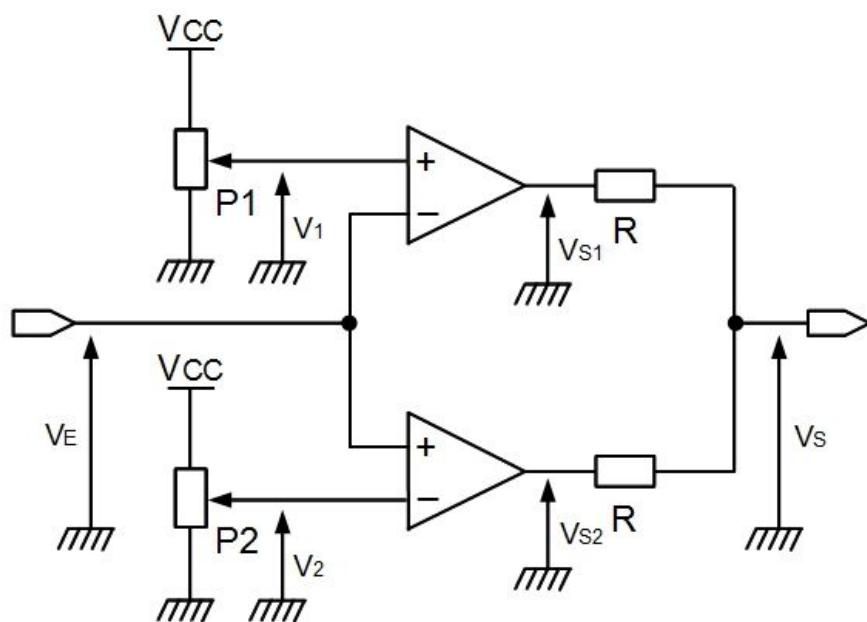
Je suis capable de :

- Mettre en équation une structure avec AOP en régime saturé
- Lire une documentation technique

O / N
O / N

Exercice 1 : Montage comparateur à fenêtre

On donne le montage suivant :



Les ALI sont alimentés en symétrique : $+V_{cc} = +12v = +Vs_{at}$ et $-V_{cc} = -12v = -Vs_{at}$.

P_1 est réglé à $2/3$ de sa course ($2/3$ de P_1 entre la borne + et la masse), et P_2 à $1/3$ de sa course.

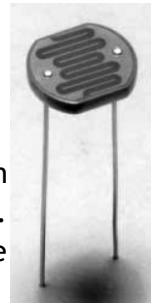
Q1 Déterminer les seuils de basculement de l'AOP 1

Q2 Tracer la caractéristiques $VS_1(VE)$.

Q3 Déterminer les seuils de basculement de l'AOP 2

Q4 Tracer la caractéristiques $VS_2(VE)$.

Q5 Exprimer VS en fonction de VS_1 et VS_2 et en déduire la caractéristique de $VS(VE)$.



Exercice 2 : Capteur de luminosité

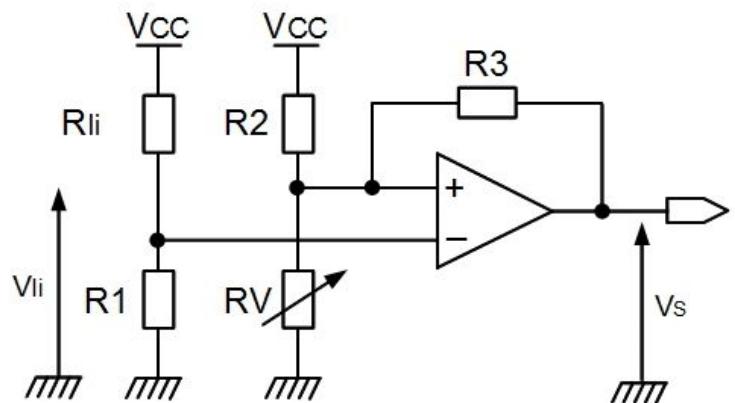
Une photorésistance (LDR) est sensible à la lumière. Sa résistance (ici R_{li}) varie en fonction de l'intensité lumineuse I_i en lux. On souhaite détecter un seuil de luminosité. Pour cela, on utilise un montage comparateur à 2 seuils, muni d'une résistance variable R_V , afin de pouvoir régler la valeur des seuils de détection.

L'ALI est alimenté en mono-tension :

$$\begin{aligned} +V_{CC} &= +5v = +V_{sat} \\ -V_{CC} &= 0v = -V_{sat} \end{aligned}$$

Dans un premier temps, on peut pour simplifier supprimer R_3 .

Q1 - Donner l'expression de V_{li} , en fonction de R_{li} et R_1



Q2 - On donne l'évolution de R_{li} en fonction de I_i dans la documentation constructeur. Tracer l'évolution de V_{li} en fonction de I_i pour $R_1 = 10K\Omega$ (dans le repère fourni ci-dessous) : attention aux échelles logarithmiques !

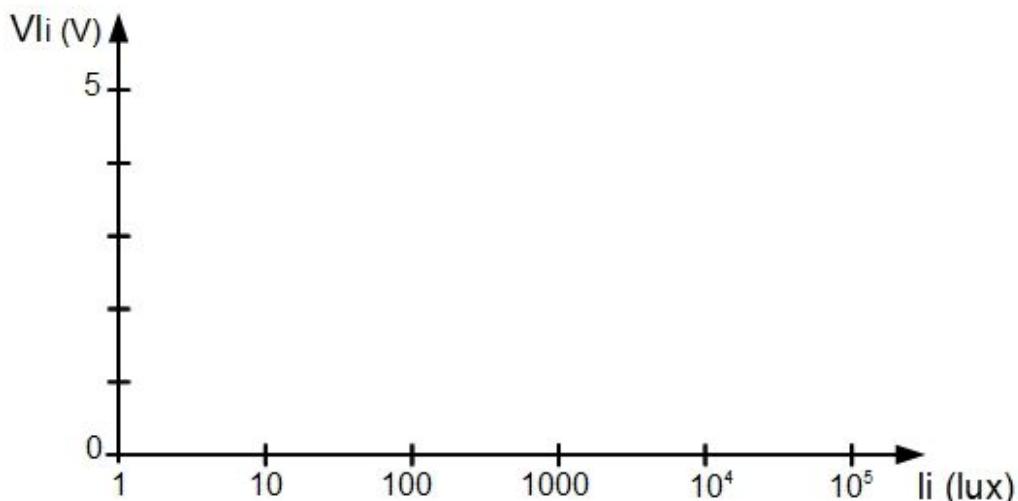
Q3 - Déterminer le seuil de basculement en fonction de R_V , R_2 .

Q4 - Pour $R_2 = 10K\Omega$, calculer R_V afin d'obtenir un seuil haut à 4v.

Q5 - Tracer la caractéristique $VS(V_{li})$.

Q6 - En déduire la valeur du seuil de luminosité détecté par le montage.

Q7 - Refaire l'étude avec R_3 . Attention, on obtiendra cette fois-ci un comparateur double seuil. Pour $R_3 = 100K\Omega$, représenter la nouvelle caractéristique $VS(V_{li})$.



160495/14 Photodiode

1/2

160495/14

2/2



Construction
The photodiode is attached to a fixture via an M12 x 1 thread. The fixture with the photoresistor is secured to a mounting base. The mounting base can be inserted on the Festo Didactik profile plate by means of a rotatable triple grip nut and T-head nut. The mounting base is fitted with three 4 mm sockets and a 3-pin miniature socket for the electrical connection.

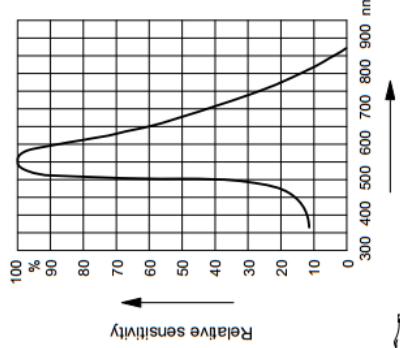
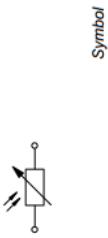
Function
The photodiode, which consists of the semiconductor material cadmium-sulphide, has a spectral responsibility similar to that of the human eye with maximum responsibility in the green spectral range of light. Photoresistors of this type are particularly suitable for the detection of visible light.
The electrical resistance changes considerably according to the illumination intensity. In the dark, the photoresistor has a high resistance and in the light a low resistance. The illumination intensity (Lux unit, in short lx) can be determined by measuring the resistance via the characteristic curve of the sensor.

Electrical connection
The photodiode is connected via one blue 4 mm socket and one black 4 mm socket.

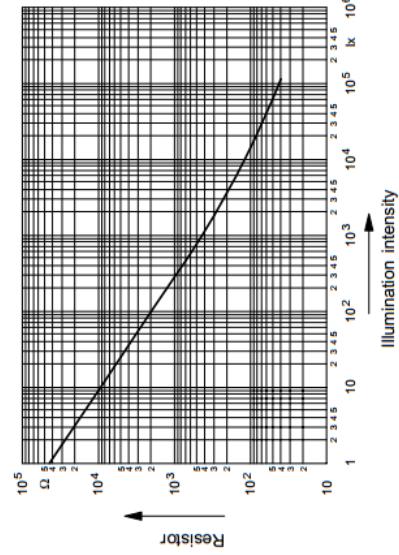
Notes
When measuring using the photodiode, the measuring current should be low in order to prevent internal temperature rise, thereby affecting the measuring results. The best way to implement this is by means of a digital multimeter.
The maximum limit values of the electrical load are to be observed when using the photodiode as a light switch. When determining the illumination intensity of different light sources with different spectral composition, deviations from the measuring results of illumination intensity meters (lux meter) may occur. Commercially available illumination intensity meters contain an optical filter, which produces a standardised, visual evaluation of the optical spectrum to DIN 5031, Part 2.

Maximum power dissipation at 30°C	250 mW
Ambient temperature	
Maximum current	75 mA
Maximum peak voltage	320 V
Typical electrical resistance with illumination by tungsten lamp of 2854°K at an ambient temperature of 25°C: at 1000 lx at 10 lx	400 Ohm 9000 Ohm
Dark resistance	> 1 MΩ
Characteristic curve in relation to resistance of illumination intensity	see diagram
Spectral responsivity	see diagram
Rise time: from darkness to 1000 lx from darkness to 10 lx	2.8 ms 18 ms
Falltime: from 1000 lx to 10-fold resistance from 10 lx to 10-fold resistance	48 ms 120 ms

Technical data



Spectral responsivity



Dependence of resistance on irradiation

The relative spectral responsivity standard has been adapted to that of the luminous efficiency of the human eye. Although the spectral responsivity of the photoresistor is similar, there are nevertheless differences on closer inspection, which can lead to varying results.

Typical values of illumination intensity:

Moonlight
Living room
Classroom
Laboratories
Electronics production, drawing offices
Sunshine with blue sky at noon

Documentation technique